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December 2013

74LCX74 Low Voltage Dual D-Type Positive Edge-Triggered Flip-Flop with 5V Tolerant Inputs

Features

- 5V tolerant inputs
- 2.3V–3.6V V_{CC} specifications provided
- 7.0ns t_{PD} max. ($V_{CC} = 3.3V$), $10\mu A I_{CC}$ max.
- Power down high impedance inputs and outputs
- ±24mA output drive (V_{CC} = 3.0V)
- Implements proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds JEDEC 78 conditions
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V
- Leadless Pb-Free DQFN package

General Description

The LCX74 is a dual D-type flip-flop with Asynchronous Clear and Set inputs and complementary (Q,\overline{Q}) outputs. Information at the input is transferred to the outputs on the positive edge of the clock pulse. After the Clock Pulse input threshold voltage has been passed, the Data input is locked out and information present will not be transferred to the outputs until the next rising edge of the Clock Pulse input.

Asynchronous Inputs:

- LOW input to SD (Set) sets Q to HIGH level
- LOW input to CD (Clear) sets Q to LOW level
- Clear and Set are independent of clock
- Simultaneous LOW on \overline{C}_D and \overline{S}_D makes both Q and \overline{Q} HIGH

Ordering Information

Order Number	Package Number	Package Description
74LCX74M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LCX74SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCX74BQX ⁽¹⁾	MLP14A	14-Terminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC MO-241, 2.5 x 3.0mm
74LCX74MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Note:

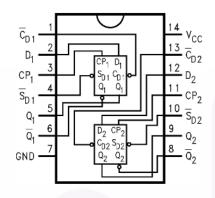
1. DQFN package available in Tape and Reel only.

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

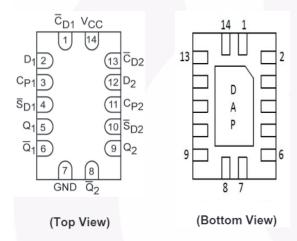
All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagrams

Pin Assignments for SOIC, SOP, and TSSOP



Pad Assignment for DQFN

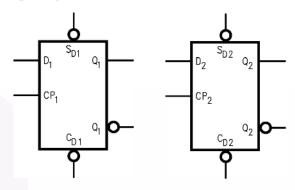


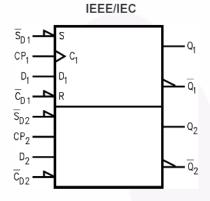
Pin Description

Pin Names	Description
D ₁ , D ₂	Data Inputs
CP ₁ , CP ₂	Clock Pulse Inputs
$\overline{C}_{D1}, \overline{C}_{D2}$	Direct Clear Inputs
$\overline{S}_{D1}, \overline{S}_{D2}$	Direct Set Inputs
$Q_1, \overline{Q}_1, Q_2, \overline{Q}_2$	Outputs
DAP	No Connect

Note: DAP (Die Attach Pad)

Logic Symbols





Truth Table

(Each Half)

	Inputs				puts
		CP	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	Н	Н
Н	Н	_	Н	Н	L
Н	Н		L	L	Н
Н	Н	L	Х	Q ₀	\overline{Q}_0

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

∠ = LOW-to-HIGH Clock Transition

 $\mathsf{Q}_0(\overline{\mathsf{Q}}_0) = \mathsf{Previous}\; \mathsf{Q}(\overline{\mathsf{Q}})$ before LOW-to-HIGH Transition of Clock

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CC}	Supply Voltage	-0.5V to +7.0V
VI	DC Input Voltage	-0.5V to +7.0V
V _O	DC Output Voltage, Output in HIGH or LOW State ⁽²⁾	-0.5V to V _{CC} + 0.5V
I _{IK}	DC Input Diode Current, V _I < GND	-50mA
I _{OK}	DC Output Diode Current	
	V _O < GND	_50mA
	$V_O > V_{CC}$	+50mA
Io	DC Output Source/Sink Current	±50mA
I _{CC}	DC Supply Current per Supply Pin	±100mA
I _{GND}	DC Ground Current per Ground Pin	±100mA
T _{STG}	Storage Temperature	−65°C to +150°C

Note:

2. IO Absolute Maximum Rating must be observed.

Recommended Operating Conditions⁽³⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Units
V _{CC}	Supply Voltage			
	Operating	2.0	3.6	V
	Data Retention	1.5	3.6	
VI	Input Voltage	0	5.5	V
V _O	Output Voltage, HIGH or LOW State	0	V _{CC}	V
I _{OH} / I _{OL}	Output Current			
	$V_{CC} = 3.0V - 3.6V$		±24	mA
	V _{CC} = 2.7V–3.0V		±12	
	V _{CC} = 2.3V–2.7V		±8	
T _A	Free-Air Operating Temperature	-40	85	°C
Δt / ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V	0	10	ns/V

Note:

3. Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

				$T_A = -40$ °C	to +85°C	
Symbol	Parameter	V _{CC} (V)	Conditions	Min.	Max.	Units
V _{IH}	HIGH Level Input Voltage	2.3–2.7		1.7		V
		2.7–3.6	1	2.0		
V_{IL}	LOW Level Input Voltage	2.3–2.7			0.7	V
		2.7–3.6			0.8	
V _{OH}	HIGH Level Output Voltage	2.3–3.6	$I_{OH} = -100 \mu A$	V _{CC} - 0.2		V
		2.3	$I_{OH} = -8mA$	1.8		
		2.7	$I_{OH} = -12mA$	2.2		
		3.0	$I_{OH} = -18mA$	2.4		
			$I_{OH} = -24mA$	2.2		
V _{OL}	LOW Level Output Voltage	2.3–3.6	$I_{OL} = 100 \mu A$		0.2	V
		2.3	$I_{OL} = 8mA$		0.6	
		2.7	I _{OL} = 12mA		0.4	
		3.0	I _{OL} = 16mA		0.4	
			I _{OL} = 24mA		0.55	
I	Input Leakage Current	2.3–3.6	$0 \le V_I \le 5.5V$		±5.0	μΑ
I _{OFF}	Power-Off Leakage Current	0	V_I or $V_O = 5.5V$		10	μΑ
I _{CC}	Quiescent Supply Current	2.3–3.6	$V_I = V_{CC}$ or GND		10	μA
			$3.6V \le V_I \le 5.5V$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	2.3–3.6	$V_{IH} = V_{CC} - 0.6V$		500	μΑ

AC Electrical Characteristics

			$T_A = -40$ °C to +85°C, $R_L = 500\Omega$						
					$V_{CC} = 2.7V,$ $C_L = 50pF$		$V_{CC} = 2.5V \pm 0.2V,$ $C_{L} = 30pF$		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Units	
f _{MAX}	Maximum Clock Frequency	150		150		150		MHz	
t _{PHL} , t _{PLH}	Propagation Delay, CP_n to Q_n or $\overline{\operatorname{Q}}_n$	1.5	7.0	1.5	8.0	1.5	8.4	ns	
t _{PHL} , t _{PLH}	Propagation Delay, \overline{C}_{Dn} or \overline{S}_{Dn} to \overline{Q}_{n} or \overline{Q}_{n}	1.5	7.0	1.5	8.0	1.5	8.4	ns	
t _S	Setup Time	2.5		2.5		4.0		ns	
t _H	Hold Time	1.5		1.5		2.0	//	ns	
t _W	Pulse Width CP	3.3		3.3		4.0		ns	
t _W	Pulse Width and \overline{C}_D , \overline{S}_D	3.3		3.6		4.0		ns	
t _{REC}	Recovery Time	2.5		3.0		4.5		ns	
t _{OSHL} , t _{OSLH}	Output to Output Skew ⁽⁴⁾		1.0					ns	

Note:

4. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

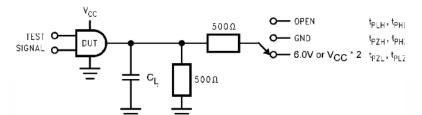
Dynamic Switching Characteristics

				$T_A = 25^{\circ}C$	
Symbol	Parameter	V _{CC} (V)	Conditions	Typical	Unit
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	3.3	$C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V$	0.8	V
		2.5	$C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V$	0.6	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	3.3	$C_L = 50 pF, V_{IH} = 3.3 V, V_{IL} = 0 V$	-0.8	V
		2.5	$C_L = 30 pF, V_{IH} = 2.5 V, V_{IL} = 0 V$	-0.6	

Capacitance

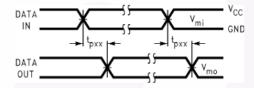
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , $f = 10MHz$	25	pF

AC Loading and Waveforms (Generic for LCX Family)

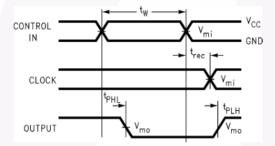


Test	Switch
$t_{\text{PLH}},t_{\text{PHL}}$	Open
t_{PZL}, t_{PLZ}	6V at V_{CC} = 3.3 ± 0.3V V_{CC} x 2 at V_{CC} = 2.5 ± 0.2V
t_{PZH},t_{PHZ}	GND

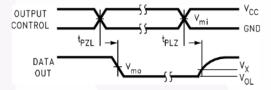
Figure 1. AC Test Circuit (C_L includes probe and jig capacitance)



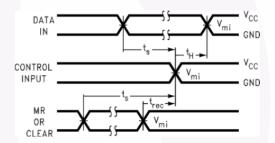
Waveform for Inverting and Non-Inverting Functions



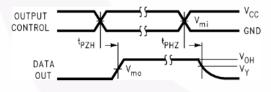
Propagation Delay. Pulse Width and trec Waveforms



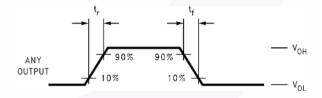
3-STATE Output Low Enable and Disable Times for Logic



Setup Time, Hold Time and Recovery Time for Logic



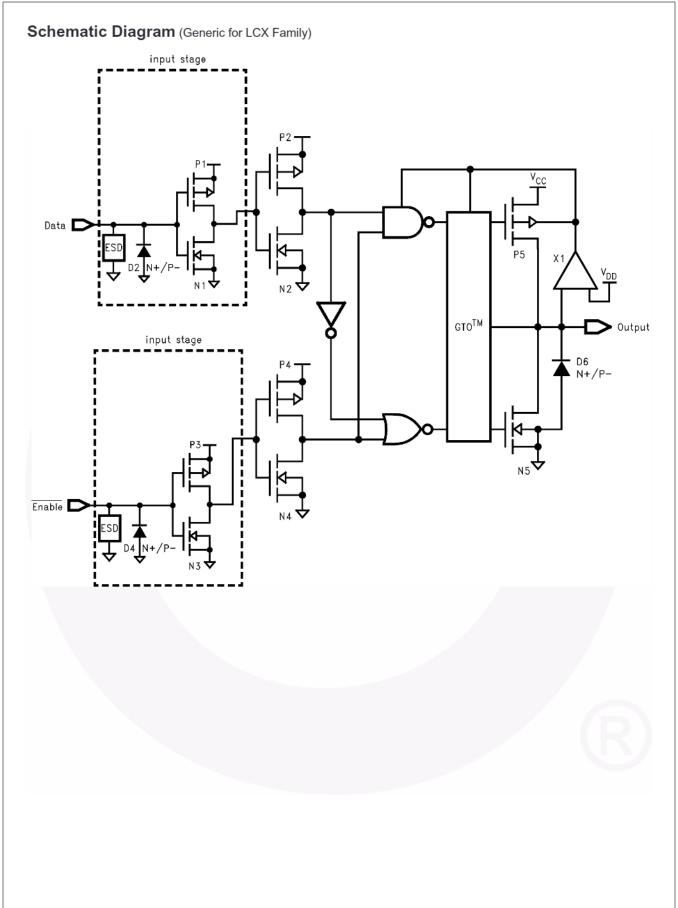
3-STATE Output High Enable and Disable Times for Logic



t_{rise} and t_{fall}

	V _{CC}				
Symbol	3.3V ± 0.3V	2.7V	2.5V ± 0.2V		
V _{mi}	1.5V	1.5V	V _{CC} /2		
V _{mo}	1.5V	1.5V	V _{CC} /2		
V_x	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V		
V _y	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V		

Figure 2. Waveforms (Input Characteristics; f = 1MHz, $t_r = t_f = 3ns$)

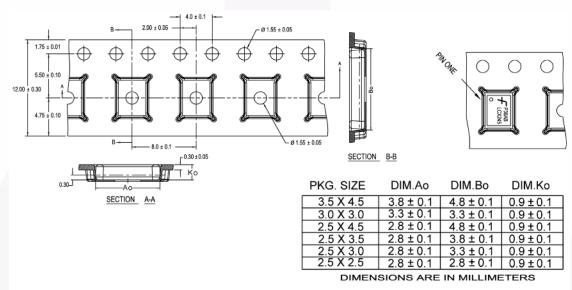


Tape and Reel Specification

Tape Format for DQFN

Package Designator	Tape Section	Number of Cavities	Cavity Status	Cover Tape Status
BQX	Leader (Start End)	125 (Typ.)	Empty	Sealed
	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (Typ.)	Empty	Sealed

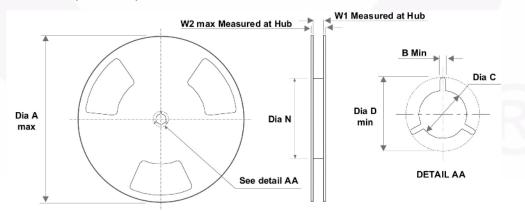
Tape Dimensions inches (millimeters)



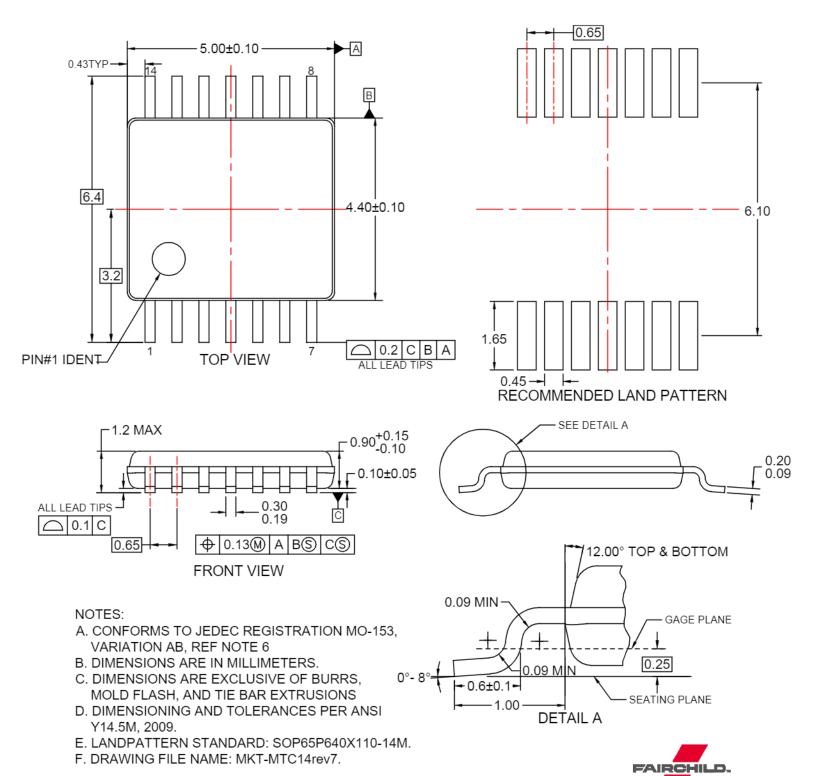
NOTES: unless otherwise specified

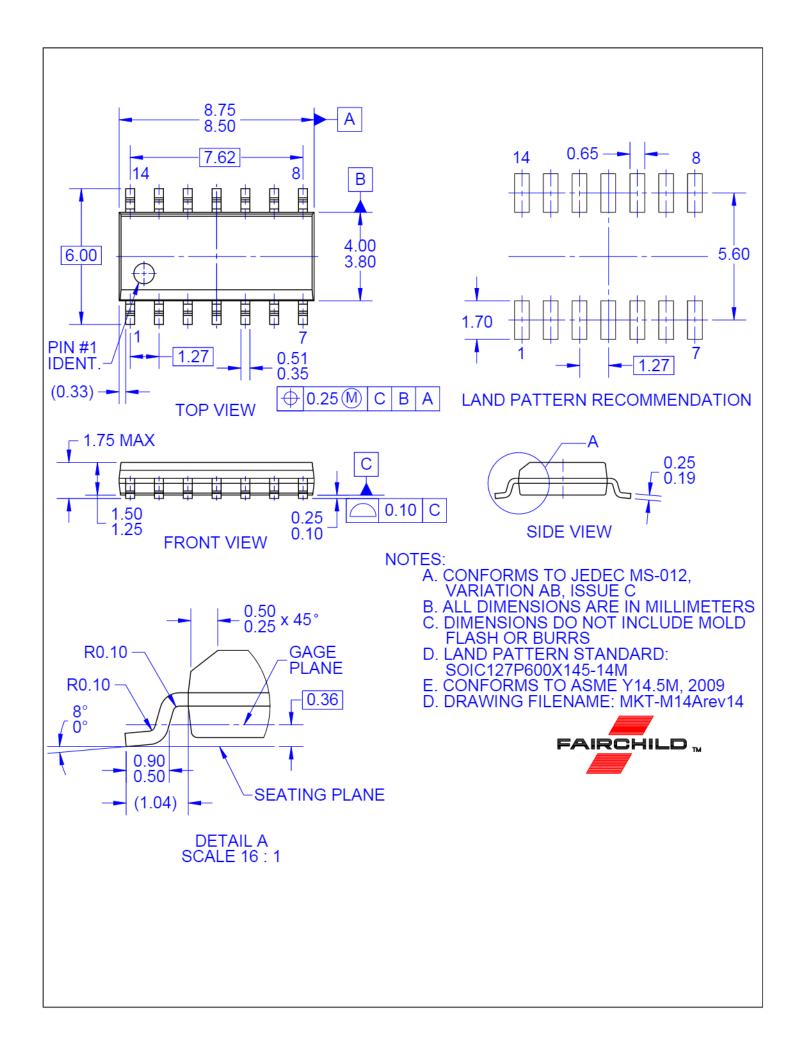
- 1. Cummulative pitch for feeding holes and cavities (chip pockets) not to exceed 0.008[0.20] over 10 pitch span.
- Smallest allowable bending radius.
- 3. Thru hole inside cavity is centered within cavity.
- 4. Tolerance is ±0.002[0.05] for these dimensions on all 12mm tapes.
- 5. Ao and Bo measured on a plane 0.120[0.30] above the bottom of the pocket.
- 6. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 7. Pocket position relative to sprocket hole measured as true position of pocket. Not pocket hole.
- 8. Controlling dimension is millimeter. Diemension in inches rounded.

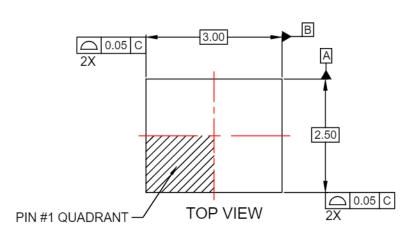
Reel Dimensions inches (millimeters)

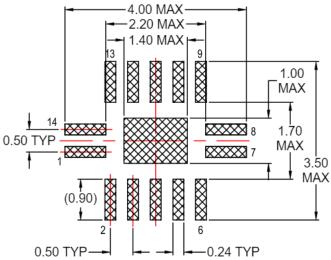


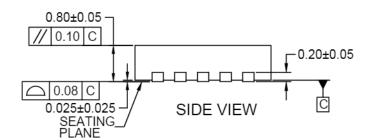
Tape Size	Α	В	С	D	N	W1	W2
12mm	13.0 (330.0)	0.059 (1.50)	0.512 (13.00)	0.795 (20.20)	2.165 (55.00)	0.488 (12.4)	0.724 (18.4)



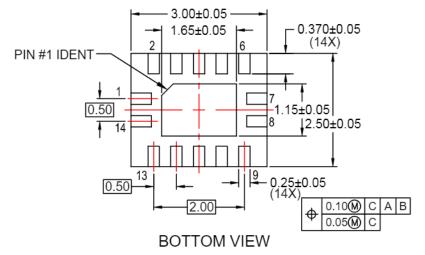








RECOMMENDED LAND PATTERN



NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-241, VARIATION AA
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
- E. DRAWING FILENAME: MKT-MLP14Arev2.



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